Unit in mm

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE (PCT PROCESS)

2 S A 1 3 0 4

POWER AMPLIFIER APPLICATIONS. VERTICAL OUTPUT APPLICATIONS.

Complementary to 2SC3296.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Collector-Base Voltage	V _{CBO}	-150	V	
Collector-Emitter Voltage	v_{CEO}	-150	V	
Emitter-Base Voltage	v_{EBO}	-5	V	
Collector Current	$I_{\mathbf{C}}$	-1.5	A	
Base Current	$I_{\mathbf{B}}$	-0.5	A	
Collector Power Ta=25°C	D. c.	2.0	w	
Dissipation Tc=25°C	$T_{\rm c} = 25^{\circ}{ m C}$			
Junction Temperature	T_{j}	150	°C	
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C	

1. BASE
2. COLLECTOR
3. EMITTER

JEDEC

TOSHIBA

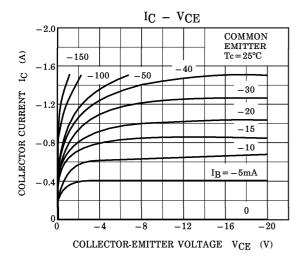
2-10L1A

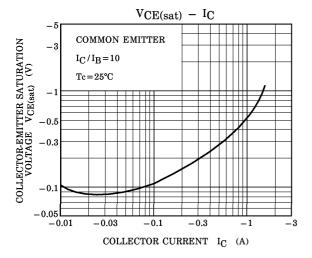
Weight: 2.1g

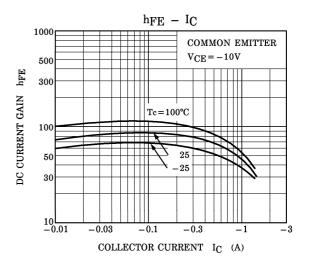
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

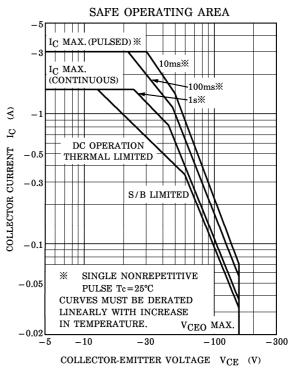
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -120V, I_{E} = 0$	_	_	-10	μ A
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5V, I_{C} = 0$	_	1	-10	μ A
DC Current Gain	${ m h_{FE}}$	$V_{CE} = -10V, I_{C} = -500mA$	40	75	140	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = -500 \text{mA}, I_{B} = -50 \text{mA}$		1	-1.5	V
Base-Emitter Voltage	$ m V_{BE}$	$V_{CE} = -10V, I_{C} = -500mA$	-0.65	-0.75	-0.85	V
Transition Frequency	${f f_T}$	$V_{CE} = -10V, I_{C} = -500mA$	_	4	_	MHz
Collector Output Capacitance	$C_{\mathbf{ob}}$	$V_{CB} = -10V, I_{E} = 0, f = 1MHz$	_	55	_	pF

1 2001-05-24









2 2001-05-24

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